

**SINGLE-PHASE GLASS PASSIVATED
SILICON BRIDGE RECTIFIER**

VOLTAGE RANGE 50 to 1000 Volts CURRENT 10 Amperes

FEATURES

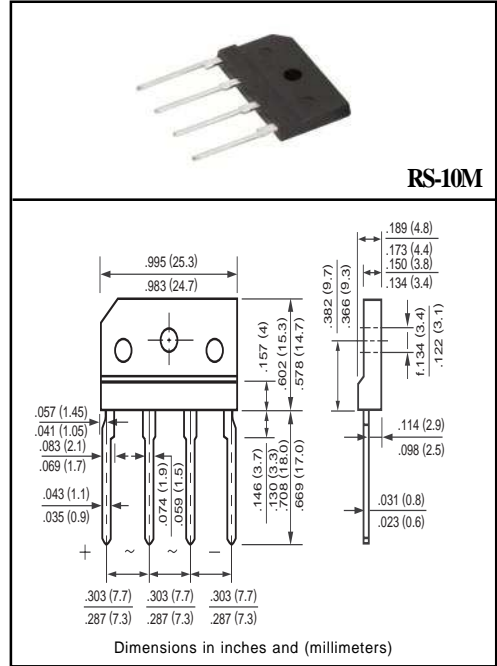
- * Low leakage
- * Low forward voltage
- * Mounting position: Any
- * Surge overload rating: 200 amperes peak
- * Silver-plated copper leads

MECHANICAL DATA

- * UL listed the recognized component directory, file #E94233
- * Epoxy: Device has UL flammability classification 94V-0

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	RS1001M	RS1002M	RS1003M	RS1004M	RS1005M	RS1006M	RS1007M	UNITS	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts	
Maximum RMS Bridge Input Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts	
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts	
Maximum Average Forward Rectified Output Current at Tc = 100°C with heatsink	I _o								10	Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}								200	Amps
Typical Thermal Resistance from junction to ambient	R _{θJA}								26	°C/W
Typical Thermal Resistance from junction to case	R _{θJC}								2.3	
Typical Thermal Resistance from junction to lead	R _{θJL}								6	
Operating and Storage Temperature Range	T _J , T _{STG}								-55 to + 150	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	RS1001M	RS1002M	RS1003M	RS1004M	RS1005M	RS1006M	RS1007M	UNITS	
Maximum Forward Voltage Drop per element at 5.0A DC	V _F					1.1				Volts
Maximum Reverse Current at Rated	I _R					5.0				uAmps
DC Blocking Voltage per element						0.2				mAmps

Note: "Fully ROHS compliant", "100% Sn plating (Pb-free)".

RATING AND CHARACTERISTIC CURVES (RS1001M THRU RS1007M)

